December 1994, Rev A FN7170

Wideband Variable-Gain Amplifier with Gain of 10

The EL4452 is a complete variable-gain circuit. It offers wide bandwidth and excellent linearity, while including a powerful output voltage amplifier, drawing modest current. The higher gain and lower input noise makes the EL4452 ideal for use in AGC systems.

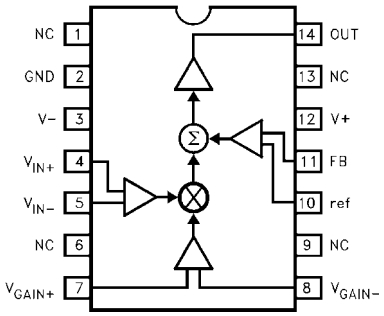
The EL4452 operates on ±5V to ±15V and has an analog input range of ±0.5V. AC characteristics do not change appreciably over the supply range.

The circuit has an operational temperature of -40°C to +85°C and is packaged in 14-pin PDIP and SO-14.

The EL4452 is fabricated with Elantec's proprietary complementary bipolar process which gives excellent signal symmetry and is very rugged.

Pinout

EL4452
(14-PIN PDIP, SO)
TOP VIEW



Features

- Complete variable-gain amplifier complete with output amplifier
- Compensated for Gain ≥ 10
- 50MHz signal bandwidth
- 50MHz gain-control bandwidth
- Low 29nV/√Hz input noise
- Operates on ±5V to ±15V supplies
- All inputs are differential
- > 70dB attenuation @ 5MHz

Applications

- AGC variable-gain amplifier
- IF amplifier
- Transducer amplifier

Ordering Information

PART NUMBER	TEMP. RANGE	PACKAGE	PKG. NO.
EL4452CN	-40°C to +85°C	14-Pin PDIP	MDP0031
EL4452CS	-40°C to +85°C	14-Pin SO	MDP0027

Absolute Maximum Ratings (T_A = 25°C)

V+	Positive Supply Voltage 16.5V	I_{OUT}	Output Current 30mA
V_S	V+ to V- Supply Voltage 33V	P_D	Maximum Power Dissipation . . . . . See Curves
V_{IN}	Voltage at any Input or Feedback . . . . . V+ to V-	T_A	Operating Temperature Range . . . . . -40°C to +85°C
ΔV_{IN}	Difference between Pairs of Inputs or Feedback. 6V	T_S	Storage Temperature Range. . . . . -60°C to +150°C
I_{IN}	Current into any Input or Feedback Pin. 4mA		

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Open-Loop DC Electrical Specifications

Power supplies at ±5V, T_A = 25°C, R_F = 910Ω, R_G = 100Ω, R_L = 500Ω

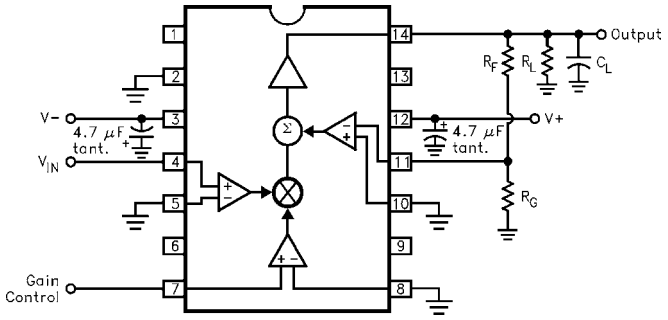
PARAMETER	DESCRIPTION		MIN	TYP	MAX	UNITS
V_{DIFF}	Signal Input Differential Input Voltage	Clipping	0.4	0.5		V
		0.6% Nonlinearity		0.4		V
V_{CM}	Common-Mode Range (All Inputs; V_{DIFF} = 0)	V_S = ±5V	±2.0	±2.8		V
		V_S = ±15V	±12.0	±12.8		V
V_{OS}	Input Offset Voltage				10	mV
V_{OS}, FB	Output Offset Voltage				10	mV
V_G, 100%	Extrapolated Voltage for 100% Gain		1.8	2.1	2.2	V
V_G, 0%	Extrapolated Voltage for 0% Gain		-0.16	-0.06	0.04	V
V_G, 1V	Gain at V_{GAIN} = 1 (R_F = 910Ω, R_G = 100Ω)		4.9	5.35	5.9	V/V
I_B	Input Bias Current (All Inputs)		-20	-9	0	µA
I_{OS}	Input Offset Current Between V_{IN}+ and V_{IN}-, V_{GAIN}+ and V_{GAIN}-			0.5	4	µA
F_T	Signal Feedthrough, V_G = -1V			-100	-70	dB
R_{IN}, Signal	Input Resistance, Signal Input		25	60		kΩ
R_{IN}, Gain	Input Resistance, Gain Input		50	120		kΩ
R_{IN}, FB	Input Resistance, Feedback		25	60		kΩ
CMRR	Common-Mode Rejection Ratio, V_{IN}		70	90		dB
PSRR	Power-Supply Rejection Ratio, V_{OS}, FB; Supplies from ±5V to ±15V		65	83		dB
E_G	Gain Error, Excluding Feedback Resistors, V_{GAIN} = 2.5V		-7		+7	%
NL	Nonlinearity, V_{IN} from -0.25V to +0.25, V_{GAIN} = 1V			0.3	0.6	%
V_O	Output Voltage Swing (V_{IN} = 0, V_{REF} Varied)	V_S = ±5V	±2.5	±2.8		V
		V_S= ±15V	±12.5	±12.8		V
I_{SC}	Output Short-Circuit Current		40	85		mA
I_S	Supply Current, V_S = ±15V			15.5	18	mA

Closed-Loop AC Electrical Specifications

Power supplies at ±12V, T_A = 25°C, R_L = 500Ω, C_L = 15pF

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNITS
BW, -3dB	-3dB Small-Signal Bandwidth, Signal Input		50		MHz
BW, ±0.1dB	0.1dB Flatness Bandwidth, Signal Input		10		MHz
Peaking	Frequency Response Peaking		0.1		dB
BW, Gain	-3dB Small-Signal Bandwidth, Gain Input		50		MHz
SR	Slew Rate, V_{OUT} between -2V and +2V	350	400	550	V/µs
V_N	Input-Referred Noise Voltage Density		29		nV/rt√Hz

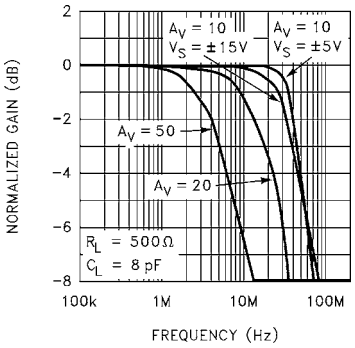
Test Circuit



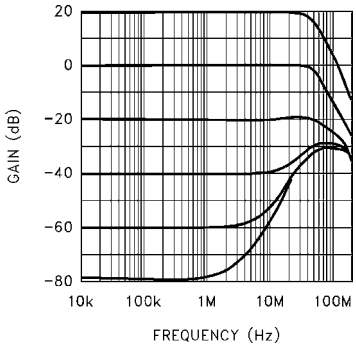
Note: For typical performance curves, R_F = 910Ω, R_G = 100Ω, V_{GAIN} = 1V, R_L = 500Ω, and C_L = 15pF unless otherwise noted.

Typical Performance Curves

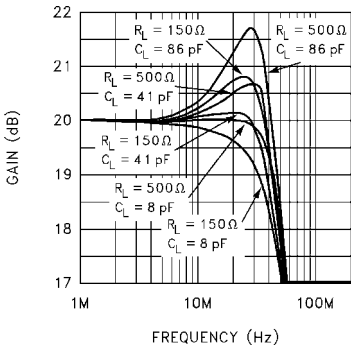
Frequency Response for Various Feedback Divider Ratios



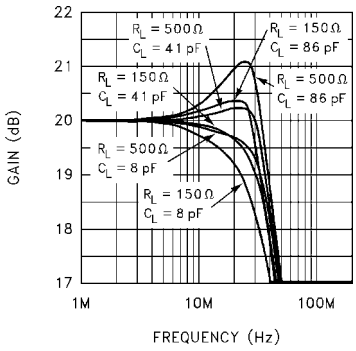
Frequency Response for Various Gains



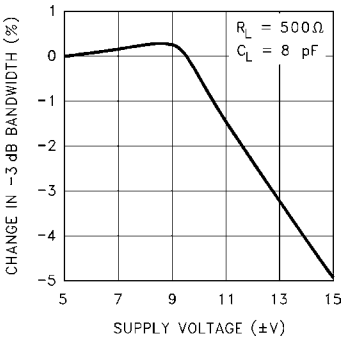
Frequency Response for Various R_L, C_L, V_S = ±5V



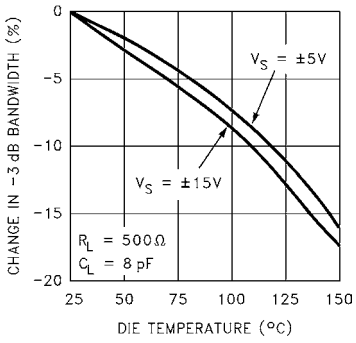
Frequency Response for Various R_L, C_L, V_S = ±15V



-3dB Bandwidth vs. Supply Voltage

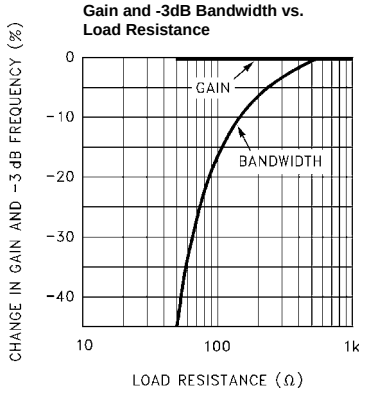


-3dB Bandwidth vs. Die Temperature

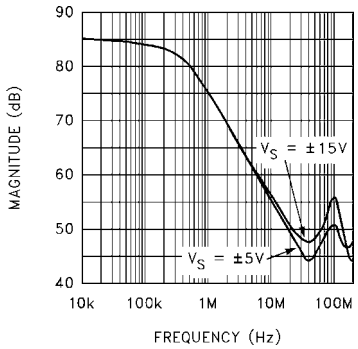


Typical Performance Curves (Continued)

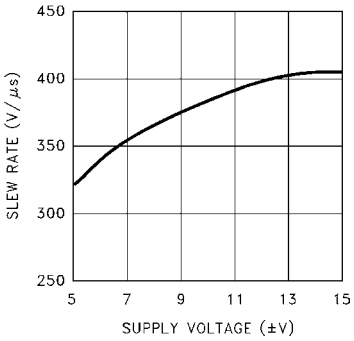
Gain and -3dB Bandwidth vs. Load Resistance



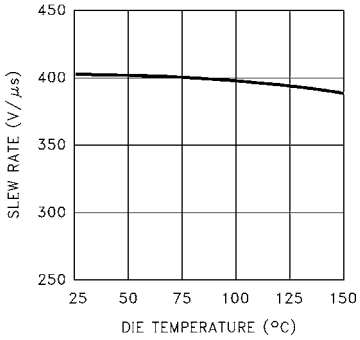
Input Common-Mode Rejection Ratio vs. Frequency



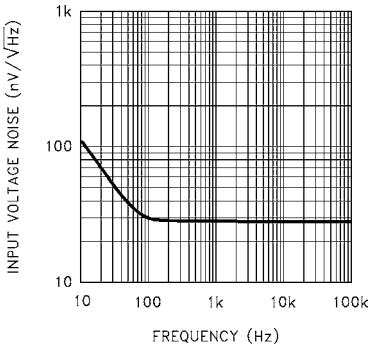
Slew Rate vs. Supply Voltage



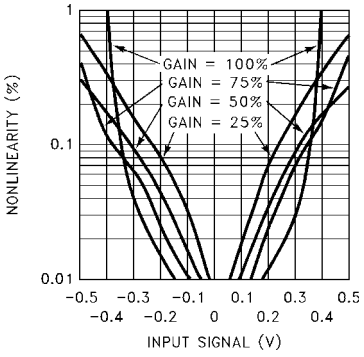
Slew Rate vs. Die Temperature



Input Voltage Noise vs. Frequency

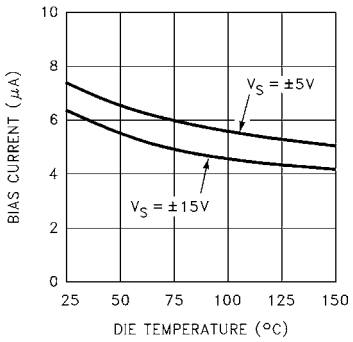


Nonlinearity vs. Input Signal

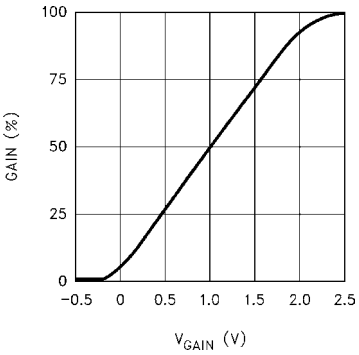


Typical Performance Curves (Continued)

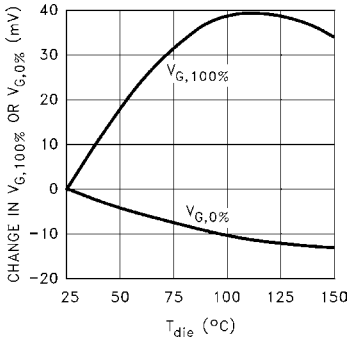
Bias Current vs. Die Temperature



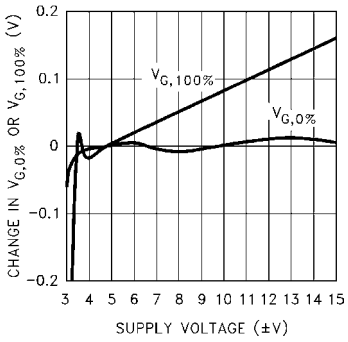
Gain vs. V_{GAIN}



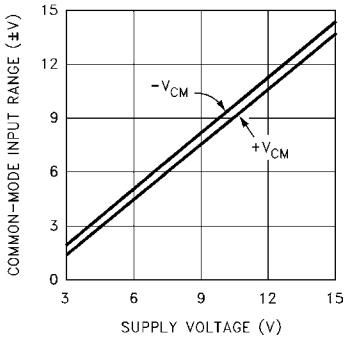
Change in $V_{G,}$ 100% and $V_{G,}$ 0% vs. Die Temperature



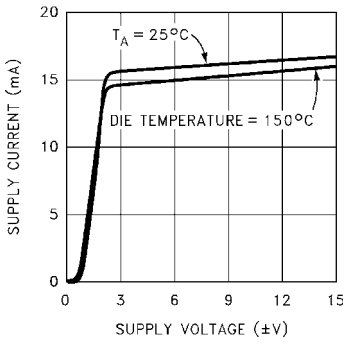
$V_{G,}$ 0% and $V_{G,}$ 100% vs. Supply Voltage



Common Mode Input Range vs. Supply Voltage

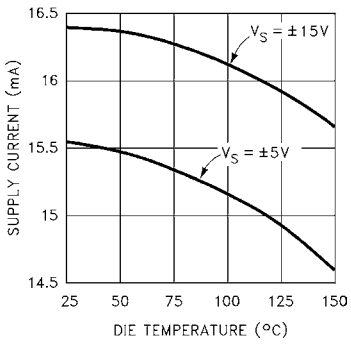


Supply Current vs. Supply Voltage

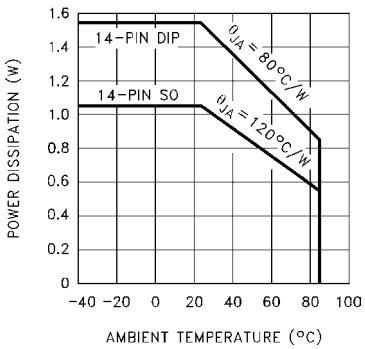


Typical Performance Curves (Continued)

Supply Current vs. Die Temperature

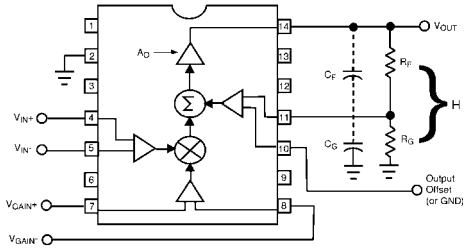


14-Pin Package Power Dissipation vs. Ambient Temperature



Applications Information

The EL4452 is a complete two-quadrant multiplier/gain control with 50MHz bandwidth. It has three sets of inputs; a differential signal input V_{IN}, a differential gain-controlling input V_{GAIN}, and another differential input which is used to complete a feedback loop with the output. Here is a typical connection:



The gain of the feedback divider is H. The transfer function of the part is:

$$V_{OUT} = A_O \times (((V_{IN}+) - (V_{IN}-)) \times ((V_{GAIN}+) - (V_{GAIN}-)) + (V_{REF} - V_{FB})).$$

V_{FB} is connected to V_{OUT} through a feedback network, so $V_{FB} = H \times V_{OUT}$. A_O is the open-loop gain of the amplifier, and is approximately 3300. The large value of A_O drives:

$$((V_{IN}+) - (V_{IN}-)) \times 1/2\ ((V_{GAIN}+) - (V_{GAIN}-)) + (V_{REF} - V_{FB}) \rightarrow 0.$$

Rearranging and substituting for V_{FB}:

$$V_{OUT} = (((V_{IN}+) - (V_{IN}-)) \times 1/2\ ((V_{GAIN}+) - (V_{GAIN})) + V_{REF})/H,$$

or

$$V_{OUT} = (V_{IN} \times 1/2\ V_{GAIN} + V_{REF})/H$$

Thus the output is equal to the difference of the V_{IN}'s times the difference of V_{GAIN}'s and offset by V_{REF}, all gained up by the feedback divider ratio. The EL4452 is stable for a divider ratio of 1/10, and the divider may be set for higher output gain, although with the traditional loss of bandwidth.

It is important to keep the feedback divider's impedance at the FB terminal low so that stray capacitance does not diminish the loop's phase margin. The pole caused by the parallel impedance of the feedback resistors and stray capacitance should be at least 130MHz; typical strays of 3pF thus require a feedback impedance of 400Ω or less. Alternatively, a small capacitor across R_F can be used to create more of a frequency-compensated divider. The value of the capacitor should scale with the parasitic capacitance at the FB input. It is also practical to place small capacitors across both the feedback and the gain resistors (whose values maintain the desired gain) to swamp out parasitics. For instance, a 3pF capacitor across R_F and 27pF to ground will dominate parasitic effects in a 1/10 divider and allow a higher divider resistance.

The REF pin can be used as the output's ground reference, for DC offsetting of the output, or it can be used to sum in another signal.

Gain-Control Characteristics

The quantity V_{GAIN} in the above equations is bounded as $0 \le V_{GAIN} \le 2$, even though the externally applied voltages exceed this range. Actually, the gain transfer function around 0 and 2V is "soft"; that is, the gain does not clip abruptly below the 0%-V_{GAIN} voltage nor above the 100%-V_{GAIN} level. An overdrive of 0.3V must be applied to V_{GAIN} to obtain truly 0% or 100%. Because the 0%- or 100%- V_{GAIN} levels cannot be precisely determined, they are extrapolated from two points measured inside the slope of the gain transfer curve. Generally, an applied V_{GAIN} range of -0.5V to +2.5V will assure the full numerical span of $0 \le V_{GAIN} \le 2$.

The gain control has a small-signal bandwidth equal to the V_{IN} channel bandwidth, and overload recovery resolves in about 20nsec.

Input Connections

The input transistors can be driven from resistive and capacitive sources, but are capable of oscillation when presented with an inductive input. It takes about 80nH of series inductance to make the inputs actually oscillate,

equivalent to four inches of unshielded wiring or 6 of unterminated input transmission line. The oscillation has a characteristic frequency of 500MHz. Often placing one's finger (via a metal probe) or an oscilloscope probe on the input will kill the oscillation. Normal high-frequency construction obviates any such problems, where the input source is reasonably close to the input. If this is not possible, one can insert series resistors of around 51Ω to de-Q the inputs.

Signal Amplitudes

Signal input common-mode voltage must be between (V-) +2.5V and (V+)-2.5V to ensure linearity. Additionally, the differential voltage on any input stage must be limited to ±6V to prevent damage. The differential signal range is ±0.5V in the EL4452. The input range is substantially constant with temperature.

The Ground Pin

The ground pin draws only 6µA maximum DC current, and may be biased anywhere between (V-)+2.5V and (V+)-3.5V. The ground pin is connected to the IC's substrate and frequency compensation components. It serves as a shield within the IC and enhances input stage CMRR and feedthrough over frequency, and if connected to a potential other than ground, it must be bypassed.

Power Supplies

The EL4452 operates with power supplies from ±3V to ±15V. The supplies may be of different voltages as long as the requirements of the ground pin are observed (see the Ground Pin section). The supplies should be bypassed close to the device with short leads. 4.7µF tantalum capacitors are very good, and no smaller bypasses need be placed in parallel. Capacitors as small as 0.01µF can be used if small load currents flow.

Single-polarity supplies, such as +12V with +5V can be used, where the ground pin is connected to +5V and V- to ground. The inputs and outputs will have to have their levels shifted above ground to accommodate the lack of negative supply.

The power dissipation of the EL4452 increases with power supply voltage, and this must be compatible with the package chosen. This is a close estimate for the dissipation of a circuit:

$$P_D = 2 \times V_S \times I_S, \max + (V_S - V_O) \times V_O / R_{PAR}$$

where

I_S, max is the maximum supply current

V_S is the ± supply voltage (assumed equal)

V_O is the output voltage

R_{PAR} is the parallel of all resistors loading the output

For instance, the EL4452 draws a maximum of 18mA. With light loading, $R_{PAR} \rightarrow \infty$ and the dissipation with ±5V supplies is 180mW. The maximum supply voltage that the device can run on for a given P_D and other parameters is:

$$V_S, \max = (P_D + V_O^2 / R_{PAR}) / (2I_S + V_O / R_{PAR})$$

The maximum dissipation a package can offer is:

$$P_D, \max = (T_J, \max - T_A, \max) / \theta_{JA}$$

Where

T_J,max is the maximum die temperature, 150°C for reliability, less to retain optimum electrical performance

T_A,max is the ambient temperature, 70°C for commercial and 85°C for industrial range

$\theta_{JA}$is the thermal resistance of the mounted package, obtained from data sheet dissipation curves

The more difficult case is the SO-14 package. With a maximum die temperature of 150°C and a maximum ambient temperature of 85°C, the 65°C temperature rise and package thermal resistance of 120°C/W gives a dissipation of 542mW at 85°C. This allows the full maximum operating supply voltage unloaded, but reduced if loaded.

Output Loading

The output stage of the EL4452 is very powerful. It can typically source 80mA and sink 120mA. Of course, this is too much current to sustain and the part will eventually be destroyed by excessive dissipation or by metal traces on the die opening. The metal traces are completely reliable while delivering the 30mA continuous output given in the Absolute Maximum Ratings table in this data sheet, or higher purely transient currents.

Gain changes only 0.2% from no load to a 100Ω load. Heavy resistive loading will degrade frequency response and distortion for loads < 100Ω.

Capacitive loads will cause peaking in the frequency response. If capacitive loads must be driven, a small-valued series resistor can be used to isolate it. 12Ω to 51Ω should suffice. A 22Ω series resistor will limit peaking to 1dB with even a 220pF load.

AGC Circuits

The basic AGC (automatic gain control) loop is this:

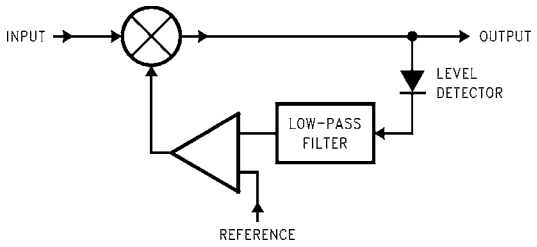


FIGURE 1. BASIC AGC LOOP

A multiplier scales the input signal and provides necessary gain and buffers the signal presented to the output load, a level detector (shown schematically here as a diode) converts some measure of the output signal amplitude to a DC level, a low-pass filter attenuates any signal ripple present on that DC level, and an amplifier compares that level to a reference and amplifies the error to create a gain-control voltage for the multiplier. The circuitry is a servo that attempts to keep the output amplitude constant by continuously adjusting the multiplier's gain control input.

Most AGC's deal with repetitive input signals that are capacitively coupled. It is generally desirable to keep DC offsets from mixing with AC signals and fooling the level detector into maintaining the DC output offset level constant, rather than a smaller AC component. To that end, either the level detector is AC-coupled, or the reference voltage must be made greater than the maximum multiplier gain times the input offset. For instance, if the level detector output equaled the reference voltage at 1V of EL4452 output, the 8mV of input offset would require a maximum gain of 125 through the EL4452. Bias current-induced offsets could increase this further.

Depending on the nature of the signal, different level detector strategies will be employed. If the system goal is to prevent overload of subsequent stages, peak detectors are preferred. Other strategies use an RMS detector to maintain constant output power. Here is a simple AGC using peak detection (Figure 2).

The output of the EL4452 drives a diode detector which is compared to V_{REF} by an offset integrator. Its output feeds the gain-control input of the EL4452. The integrator's output is attenuated by the 2kΩ and 2.7kΩ resistors to prevent the op-amp from overloading the gain-control pin during zero input conditions. The 510kΩ resistor provides a pull-down current to the peak level storage capacitor C1 to allow it to drift negative when output amplitude reduces. Thus the detector is of fast attack and slow decay design, able to reduce AGC gain rapidly when signal amplitude suddenly increases, and increases gain slowly when the input drops out momentarily. The value of C1 determines drop-out reaction rates, and the value of C_F affects overall loop time constant as well as the amount of ripple on the gain-control line. C2 can be used to reduce this ripple further, although it contributes to loop overshoot when input amplitude changes suddenly. The op-amp can be any inexpensive low-frequency type.

The major problem with diode detectors is their large and variable forward voltage. They require at least a $2V_{P-P}$ peak output signal to function reliably, and the forward voltage should be compensated by including a negative V_D added to V_{REF}. Even this is only moderately successful. At the expense of bandwidth, op-amp circuits can greatly improve diode rectifiers (see "An Improved Peak Detector", an

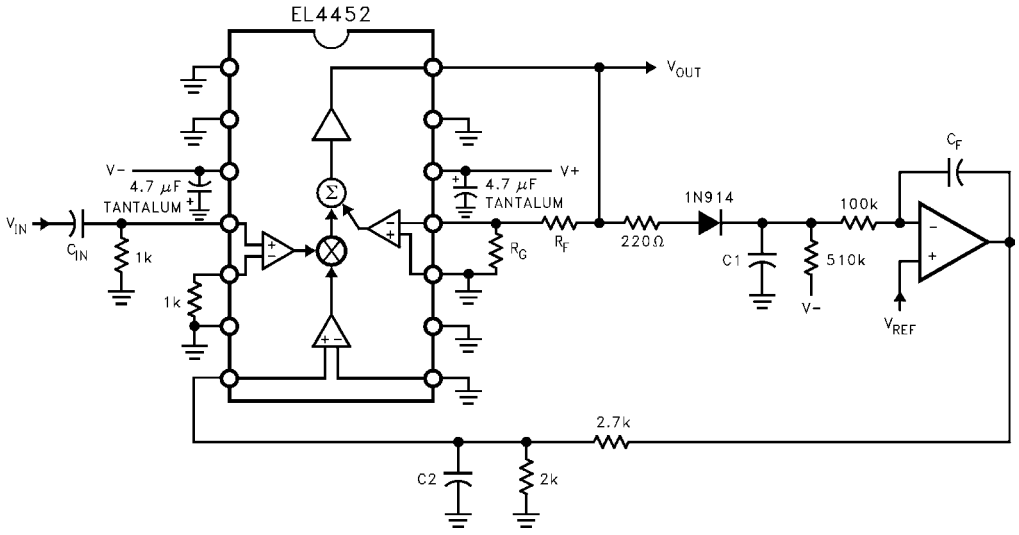


FIGURE 2.

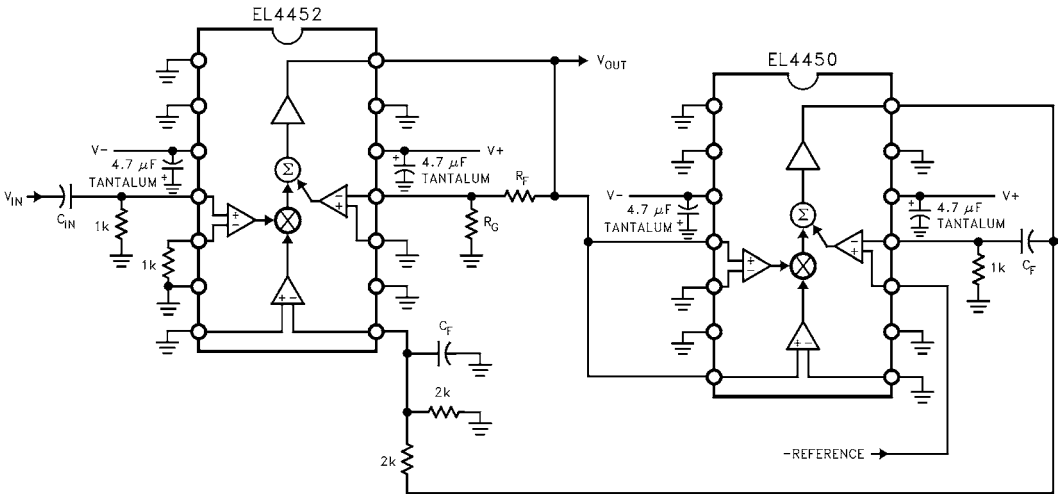


FIGURE 3.

Elantec application note). Fortunately, the detector will see a constant amplitude of signal if the AGC is operating correctly.

A better-calibrated method is to use a four-quadrant multiplier as a square-law detector. Here is a circuit employing the EL4450 (Figure 3).

In this circuit, the EL4450 not only calculates the square of the input, but also provides the offset integrator function. The product of the two multiplier inputs adds to the -Reference input and are passed to the output amplifier, which through C_F behaves as a pseudo-integrator. The “integrator” gain does not pass through zero at high frequencies but has a zero at $1/(2\pi C_F \times 1k\Omega)$. This zero is cancelled by the pole caused by the second capacitor of value C_F connected at the EL4452 $-V_{GAIN}$ input. The -Reference can be exchanged for a positive reference by connecting it to the ground return of the 1kΩ resistor at the FB terminal and grounding REF.

As a general consideration, the input signal applied to an EL4452 should be kept below about 250mV peak for good linearity. If the AGC were designed to produce a 1V peak output, the input range would be 100mV–250mV peak when the EL4452 has a feedback network that establishes a maximum gain of 10. This is an input range of only 2.5:1 for precise output regulation. Raising the maximum gain to 25 allows a 40mV–250mV input range with the output still regulated, better than 6:1. Unfortunately, the bandwidth will be reduced. Bandwidth can be maintained by adding a high frequency op-amp cascaded with the output to make up gain beyond the 10 of the EL4452, current feedback devices being the most flexible. The op-amp’s input should be capacitor coupled to prevent gained-up offsets from confusing the level detector during AGC control line variations.